

具有复位功能的 CDx4HC(T)273 高速 CMOS 逻辑八路 D 型触发器

1 特性

- 通用时钟和异步控制器复位
- 正边沿触发
- 缓冲输入
- 扇出 (在温度范围内)
 - 标准输出: 10 个 LSTTL 负载
 - 总线驱动器输出: 15 个 LSTTL 负载
- 宽工作温度范围: -55°C 至 125°C
- 平衡的传播延迟及转换时间
- 与 LSTTL 逻辑 IC 相比, 可显著降低功耗
- HC 类型:
 - 工作电压为 2V 至 6V
 - 高抗噪性: 当 $V_{CC} = 5V$ 时, $N_{IL} = 30\%$, $N_{IH} = V_{CC}$ 的 30%
- HCT 类型:
 - 工作电压为 4.5V 至 5.5V
 - 直接 LSTTL 输入逻辑兼容性, $V_{IL} = 0.8V$ (最大值), $V_{IH} = 2V$ (最小值)
 - CMOS 输入兼容性, 当电压为 V_{OL} 、 V_{OH} 时, $I_I \leq 1 \mu A$

2 说明

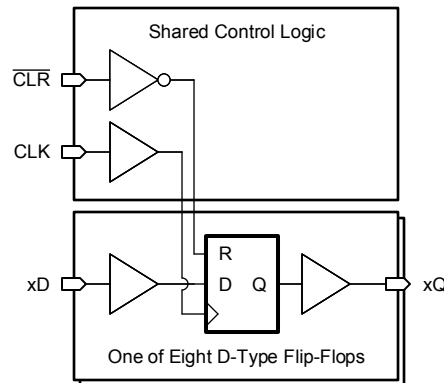
HC273 和 HCT273 高速八路 D 型触发器具有直接清零输入, 使用硅栅 CMOS 技术制造而成。它们具有标准 CMOS 集成电路的低功耗特性。

D 输入端的信息在时钟脉冲的上升沿传输到 Q 输出端。所有八个触发器均由通用时钟 (CLK) 和通用复位 (CLR) 控制。复位通过低电压电平完成, 与时钟无关。所有八个 Q 输出端可复位至逻辑 0。

器件信息

器件型号	封装 ⁽¹⁾	封装尺寸 (标称值)
CD54HC273F	CDIP (20)	26.92mm × 6.92mm
CD74HC273M	SOIC (20)	12.80mm × 7.50mm
CD74HC273E	PDIP (20)	25.40mm × 6.35mm
CD74HCT273M	SOIC (20)	12.80mm × 7.50mm
CD74HCT273	PDIP (20)	25.40mm × 6.35mm

(1) 如需了解所有可用封装, 请参阅数据表末尾的可订购产品附录。



功能方框图



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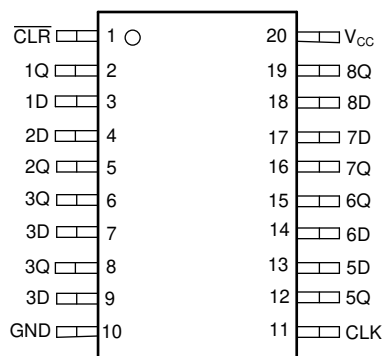
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3 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision B (May 2003) to Revision C (December 2021)	Page
• 更新了整个文档中的编号、格式、表格、图和交叉参考，以反映现代数据表标准.....	1
• 更新了引脚名称，以符合现行的 TI 命名约定 <u>MR</u> 更新为 <u>CLR</u> 、Q0 更新为 1Q、D0 更新为 1D、D1 更新为 2D、Q1 更新为 2Q、Q2 更新为 3Q、D2 更新为 3Q、D3 更新为 4D、Q3 更新为 4Q、CP 更新为 CLK、Q4 更新为 5Q、D4 更新为 5D、D5 更新为 D6、Q5 更新为 6Q、Q6 更新为 7Q、D6 更新为 7D、D7 更新为 8D、Q7 更新为 8Q.....	1
• Junction-to-ambient thermal resistance values increased. DW was 58 is now 109.1, N was 69 is now 84.6....	4

4 Pin Configuration and Functions



**J, DW or N package
20-Pin CDIP, PDIP or SOIC
Top View**

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage		- 0.5	7	V
I _{IK}	Input clamp diode current	For V _I < - 0.5 V or V _I > V _{CC} + 0.5 V		±20	mA
I _{OK}	Output clamp diode current	For V _O < - 0.5 V or V _O > V _{CC} + 0.5 V		±20	mA
I _O	Drain current, per output	For - 0.5 V < V _O < V _{CC} + 0.5 V		±25	mA
I _O	Output source or sink current per output pin	For V _O > - 0.5 V or V _O < V _{CC} + 0.5 V		±25	mA
	Continuous current through V _{CC} or ground current			±50	mA
T _J	Junction temperature			150	°C
T _{stg}	Storage temperature range		- 65	150	°C
	Lead temperature (Soldering 10s) (SOIC - Lead Tips Only)			300	°C

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 Recommended Operating Conditions

			MIN	MAX	UNIT
T _A	Temperature range		- 55	125	°C
V _{CC}	Supply voltage range	HC types	2	6	V
		HCT types	4.5	5.5	
V _I , V _O	DC input or output voltage		0	V _{CC}	V
t _i	Input rise and fall time	2 V		1000	ns
		4.5 V		500	
		6 V		400	

5.3 Thermal Information

THERMAL METRIC		SN74HC(T)273		UNIT
		DW (SOIC)	N (PDIP)	
		20 PINS	20 PINS	
R _{θJA}	Junction-to-ambient thermal resistance ⁽¹⁾	109.1	84.6	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	76	72.5	°C/W
R _{θJB}	Junction-to-board thermal resistance	77.6	65.3	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	51.5	55.3	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	77.1	65.2	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC package thermal metrics](#) application report.

5.4 Electrical Characteristics

PARAMETER		TEST CONDITIONS ⁽²⁾	V _{CC} (V)	25°C			- 40°C to 85°C		- 55°C to 125°C		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
HC TYPES											
V _{IH}	High level input voltage		2	1.5			1.5		1.5		V
			4.5	3.15			3.15		3.15		
			6	4.2			4.2		4.2		
V _{IL}	Low level input voltage		2	0.5			0.5		0.5		V
			4.5	1.35			1.35		1.35		
			6	1.8			1.8		1.8		
V _{OH}	High level output voltage CMOS loads	I _{OH} = - 20 μA	2	1.9			1.9		1.9		V
		I _{OH} = - 20 μA	4.5	4.4			4.4		4.4		
		I _{OH} = - 20 μA	6	5.9			5.9		5.9		
	High level output voltage TTL loads	I _{OH} = - 4 mA	4.5	3.98			3.84		3.7		V
		I _{OH} = - 5.2 mA	6	5.48			5.34		5.2		
V _{OL}	Low level output voltage CMOS loads	I _{OL} = 20 μA	2	0.1			0.1		0.1		V
		I _{OL} = 20 μA	4.5	0.1			- 0.1		- 0.1		
		I _{OL} = 20 μA	6	0.1			0.1		0.1		
	Low level output voltage TTL loads	I _{OL} = 4 mA	4.5	0.26			0.33		0.4		V
		I _{OL} = 5.2 mA	6	0.26			0.33		0.4		
I _I	Input leakage current	V _I = V _{CC} or GND	6	±0.1			±1		±1		mA
I _{CC}	Quiescent device current	V _I = V _{CC} or GND	6	8			80		160		mA
HCT TYPES											
V _{IH}	High level input voltage		4.5 to 5.5	2			2		2		V
V _{IL}	Low level input voltage		4.5 to 5.5	0.8			0.8		0.8		V
V _{OH}	High level output voltage CMOS loads	I _{OH} = - 20 μA	4.5	4.4			4.4		4.4		V
	High level output voltage TTL loads	I _{OH} = - 4 mA	4.5	3.98			3.84		3.7		
V _{OL}	Low level output voltage CMOS loads	I _{OL} = 20 μA	4.5	0.1			0.1		0.1		V
	Low level output voltage TTL loads	I _{OL} = 4 mA	4.5	0.26			0.33		0.4		
I _I	Input leakage current	V _I = V _{CC} or GND	5.5	±0.1			±1		±1		μA
I _{CC}	Quiescent device current	V _I = V _{CC} or GND	5.5	8			80		160		μA

5.4 Electrical Characteristics (continued)

PARAMETER		TEST CONDITIONS ⁽²⁾	V _{CC} (V)	25°C			– 40°C to 85°C		– 55°C to 125°C		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
ΔI_{CC} ⁽¹⁾	Additional quiescent device current per input pin	CLR input held at V _{CC} – 2.1	4.5 to 5.5		100	540		675		735	μ A
		Data inputs held at V _{CC} – 2.1	4.5 to 5.5		100	144		180		196	μ A
		CLK inputs held at V _{CC} – 2.1	4.5 to 5.5		100	540		675		735	μ A

(1) For dual-supply systems theoretical worst case (V_I = 2.4 V, V_{CC} = 5.5 V) specification is 1.8mA.

(2) V_I = V_{IH} or V_{IL}, unless otherwise noted.

5.5 Prerequisite for Switching Characteristics

See [Parameter Measurement Information](#)

PARAMETER		V _{CC} (V)	25°C			– 40°C to 85°C		– 55°C to 125°C		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
HC TYPES										
f _{MAX}	Maximum clock frequency	2	6			5		4		MHz
		4.5	30			25		20		
		6	35			29		23		
t _W	CLR pulse width	2	60			75		90		ns
		4.5	12			15		18		
		6	10			13		15		
t _W	Clock pulse width	2	80			100		120		ns
		4.5	16			20		24		
		6	14			17		20		
t _{SU}	Set-up time data to clock	2	60			75		70		ns
		4.5	12			15		18		
		6	10			13		15		
t _H	Hold time, data to clock	2	3			3		3		ns
		4.5	3			3		3		
		6	3			3		3		
t _{REM}	Removal time, CLR to clock	2	50			65		75		ns
		4.5	10			13		15		
		6	9			11		13		
HCT TYPES										
f _{MAX}	Maximum clock frequency	4.5	25			20		16		MHz
t _W	CLR pulse width	4.5	12			15		18		ns
t _W	Clock pulse width	4.5	20			25		30		ns
t _{SU}	Set-up time data to clock	4.5	12			15		18		ns
t _H	Hold time, data to clock	4.5	3			3		3		ns
t _{REM}	Removal time, CLR to clock	4.5	10			13		15		ns

5.6 Switching Characteristics

Input t_r , t_f = 6 ns (See [Parameter Measurement Information](#))

PARAMETER		TEST CONDITIONS	V _{CC} (V)	25°C		- 40°C to 85°C	- 55°C to 125°C	UNIT
				TYP	MAX	MAX	MAX	
HC TYPES								
t _{PLH} , t _{PHL}	Propagation delay Clock to output	C _L = 50 pF	2	150	190	225	ns	
			4.5	30	38	45		
			6	26	30	38		
		C _L = 15 pF	5	12				
t _{PHL}	Propagation delay CLR to output	C _L = 50 pF	2	150	190	225	ns	
			4.5	30	38	45		
			6	26	30	38		
t _{TLH} , t _{THL}	Output transition time	C _L = 50 pF	2	75	95	110	ns	
			4.5	15	19	22		
			6	13	16	19		
C _{IN}	Input capacitance			10	10	10	pF	
f _{MAX}	Maximum clock frequency	C _L = 15 pF	5	60			MHz	
C _{PD}	Power dissipation capacitance ^{(1) (2)}		5	25			pF	
HCT TYPES								
t _{PLH} , t _{PHL}	Propagation delay, Clock to output	C _L = 50 pF	4.5	30	38	45	ns	
		C _L = 15 pF	5	12				
t _{PHL}	Propagation delay, CLR to output	C _L = 50 pF	4.5	32	40	48	ns	
t _{TLH} , t _{THL}	Output transition time	C _L = 50 pF	4.5	15	19	22	ns	
C _{IN}	Input capacitance			10	10	10	pF	
f _{MAX}	Maximum clock frequency	C _L = 15 pF	5	50			MHz	
C _{PD}	Power dissipation capacitance ^{(1) (2)}		5	25			pF	

(1) C_{PD} is used to determine the dynamic power consumption, per flip-flop.

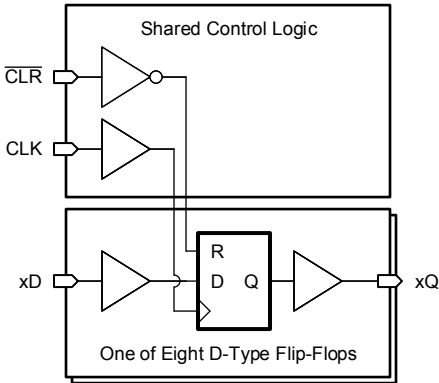
(2) $P_D = C_{PD} V_{CC}^2 f_i + \sum (C_L V_{CC}^2 + f_o)$ where f_i = input frequency, f_o = output frequency, C_L = output load capacitance, V_{CC} = supply voltage.

6 Detailed Description

6.1 Overview

The ' HC273 and ' HCT273 high speed octal D-Type flip-flops with a direct clear input are manufactured with silicon-gate CMOS technology. They possess the low power consumption of standard CMOS integrated circuits. Information at the D input is transferred to the Q outputs on the positive-going edge of the clock pulse. All eight flip-flops are controlled by a common clock (CLK) and a common reset (CLR). Resetting is accomplished by a low voltage level independent of the clock. All eight Q outputs are reset to a logic 0.

6.2 Functional Block Diagram



6.3 Device Functional Modes

表 6-1. Truth Table⁽¹⁾

INPUTS			OUTPUT
RESET ($\overline{\text{CLR}}$)	CLOCK CLK	DATA D_n	Q
L	X	X	L
H	↑	H	H
H	↑	L	L
H	L	X	Q_0

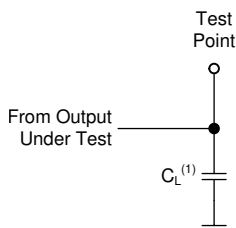
(1) H = high voltage level, L = low voltage level, X = don't care, ↑ = transition from low to high level, Q_0 = level before the indicated steady-state input conditions were established

7 Parameter Measurement Information

Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: $PRR \leq 1 \text{ MHz}$, $Z_O = 50 \Omega$, $t_f < 6 \text{ ns}$.

For clock inputs, $f_{\max}$ is measured when the input duty cycle is 50%.

The outputs are measured one at a time with one input transition per measurement.



(1) C_L includes probe and test-fixture capacitance.

图 7-1. Load Circuit for Push-Pull Outputs

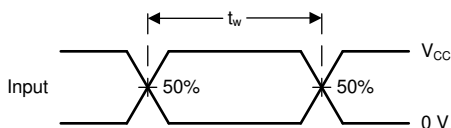


图 7-2. Voltage Waveforms, Standard CMOS Inputs
Pulse Duration

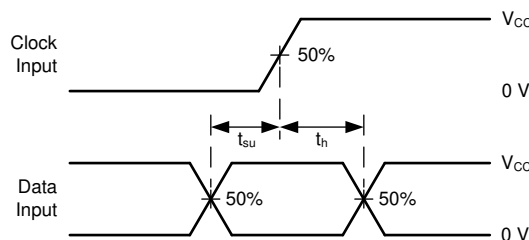
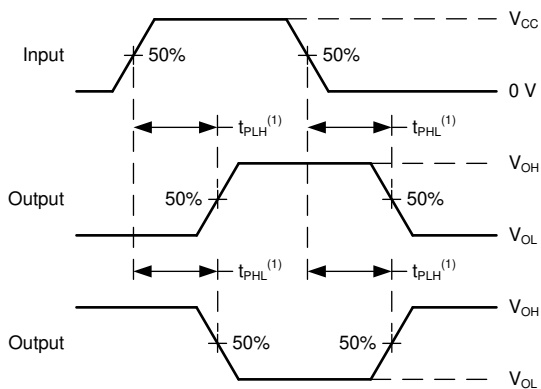
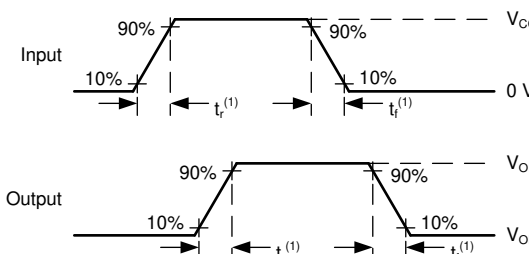


图 7-3. Voltage Waveforms, Standard CMOS Inputs
Setup and Hold Times



(1) The greater between t_{PLH} and t_{PHL} is the same as t_{pd} .

图 7-4. Voltage Waveforms, Propagation Delays for
Standard CMOS Inputs



(1) The greater between t_r and t_f is the same as t_t .

图 7-5. Voltage Waveforms, Input and Output
Transition Times for Standard CMOS Inputs

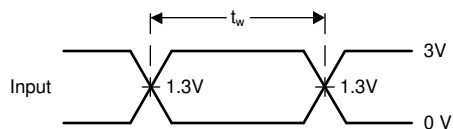


图 7-6. Voltage Waveforms, TTL-Compatible CMOS Inputs Pulse Duration

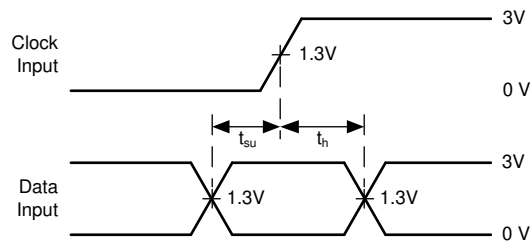
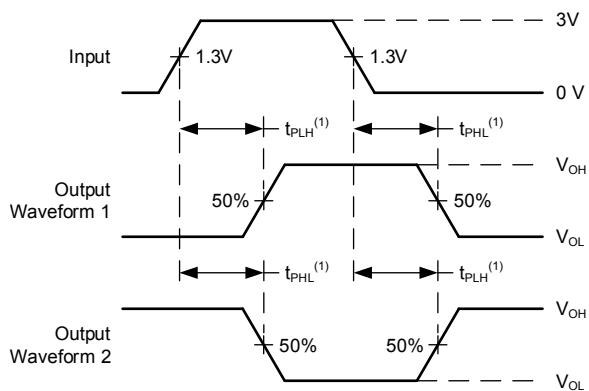


图 7-7. Voltage Waveforms, TTL-Compatible CMOS Inputs Setup and Hold Times



(1) The greater between t_{PLH} and t_{PHL} is the same as t_{pd} .

图 7-8. Voltage Waveforms, Propagation Delays for TTL-Compatible Inputs

8 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1- μ F capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1- μ F and 1- μ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

9 Layout

9.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC} , whichever makes more sense for the logic function or is more convenient.

10 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

10.1 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击 [订阅更新](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

10.2 支持资源

[TI E2E™ 支持论坛](#) 是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的《使用条款》。

10.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

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10.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

10.5 术语表

[TI 术语表](#) 本术语表列出并解释了术语、首字母缩略词和定义。

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
5962-8772501RA	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8772501RA CD54HCT273F3A
CD54HC273F	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD54HC273F
CD54HC273F.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD54HC273F
CD54HC273F3A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8409901RA CD54HC273F3A
CD54HC273F3A.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8409901RA CD54HC273F3A
CD54HCT273F	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD54HCT273F
CD54HCT273F.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD54HCT273F
CD54HCT273F3A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8772501RA CD54HCT273F3A
CD54HCT273F3A.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8772501RA CD54HCT273F3A
CD74HC273E	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU NIPDAU	N/A for Pkg Type	-55 to 125	CD74HC273E
CD74HC273E.A	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HC273E
CD74HC273M	Obsolete	Production	SOIC (DW) 20	-	-	Call TI	Call TI	-55 to 125	HC273M
CD74HC273M96	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC273M
CD74HC273M96.A	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC273M
CD74HC273M96E4	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC273M
CD74HCT273E	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU NIPDAU	N/A for Pkg Type	-55 to 125	CD74HCT273E
CD74HCT273E.A	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HCT273E
CD74HCT273E.B	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HCT273E
CD74HCT273EE4	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HCT273E
CD74HCT273M	Obsolete	Production	SOIC (DW) 20	-	-	Call TI	Call TI	-55 to 125	HCT273M
CD74HCT273M96	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT273M
CD74HCT273M96.A	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT273M

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

(2) Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) RoHS values: Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF CD54HC273, CD54HCT273, CD74HC273, CD74HCT273 :

- Catalog : [CD74HC273](#), [CD74HCT273](#)
- Military : [CD54HC273](#), [CD54HCT273](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Military - QML certified for Military and Defense Applications

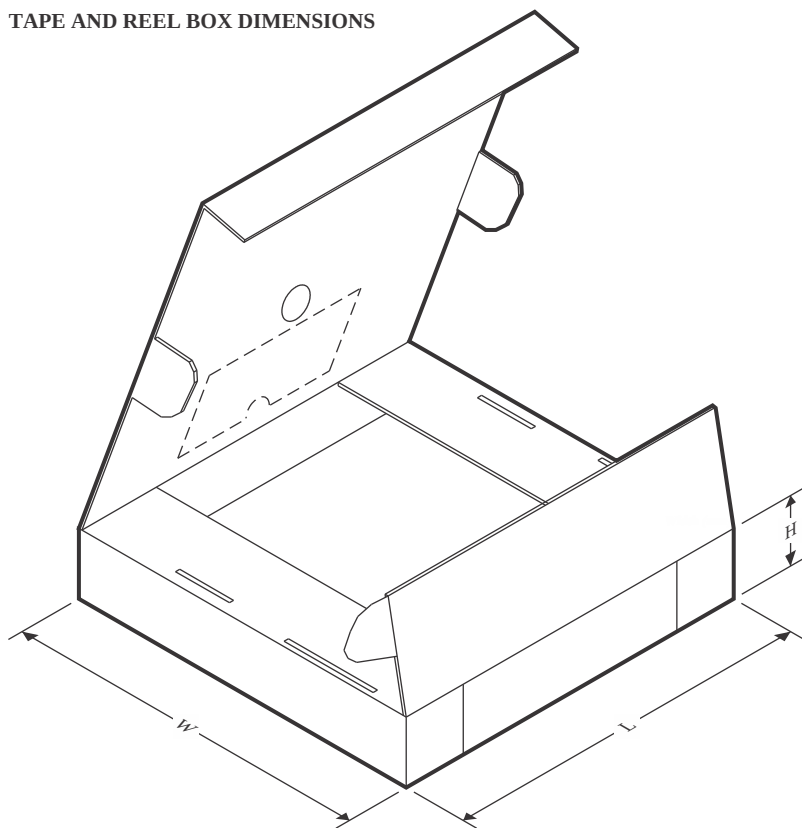
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC273M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
CD74HC273M96	SOIC	DW	20	2000	330.0	24.4	10.9	13.3	2.7	12.0	24.0	Q1
CD74HCT273M96	SOIC	DW	20	2000	330.0	24.4	10.9	13.3	2.7	12.0	24.0	Q1
CD74HCT273M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1

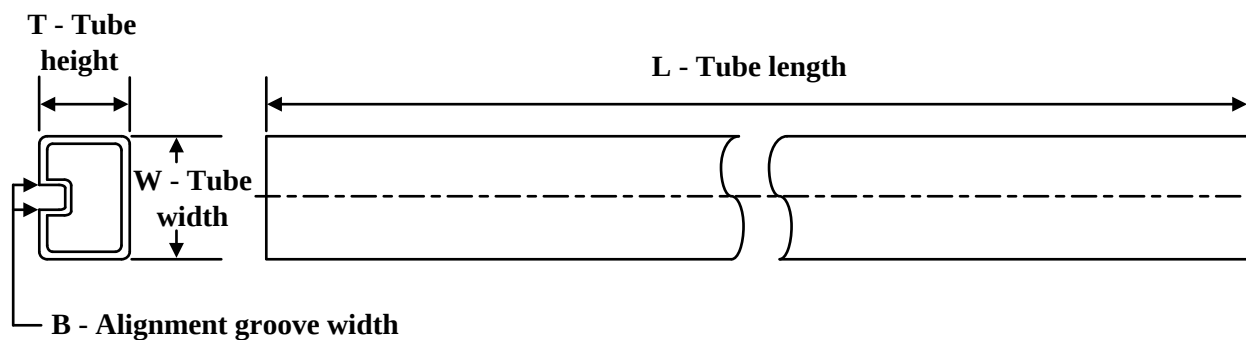
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC273M96	SOIC	DW	20	2000	356.0	356.0	45.0
CD74HC273M96	SOIC	DW	20	2000	356.0	356.0	45.0
CD74HCT273M96	SOIC	DW	20	2000	356.0	356.0	45.0
CD74HCT273M96	SOIC	DW	20	2000	356.0	356.0	45.0

TUBE



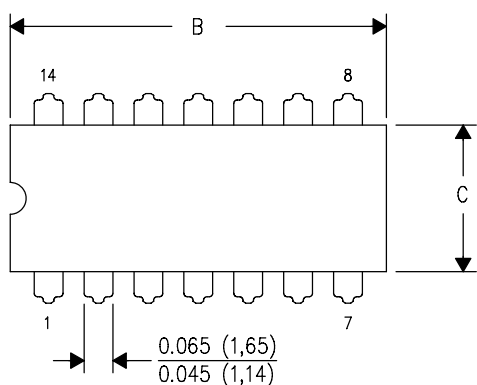
*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
CD74HC273E	N	PDIP	20	20	506	13.97	11230	4.32
CD74HC273E.A	N	PDIP	20	20	506	13.97	11230	4.32
CD74HCT273E	N	PDIP	20	20	506	13.97	11230	4.32
CD74HCT273E.A	N	PDIP	20	20	506	13.97	11230	4.32
CD74HCT273E.B	N	PDIP	20	20	506	13.97	11230	4.32
CD74HCT273EE4	N	PDIP	20	20	506	13.97	11230	4.32

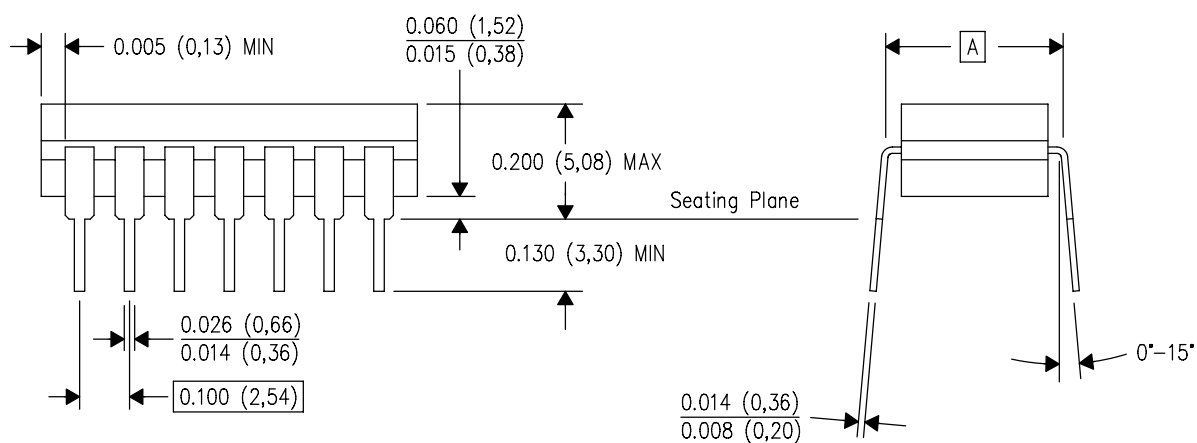
J (R-GDIP-T**)

14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



PINS ** DIM	14	16	18	20
A	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC
B MAX	0.785 (19,94)	.840 (21,34)	0.960 (24,38)	1.060 (26,92)
B MIN	—	—	—	—
C MAX	0.300 (7,62)	0.300 (7,62)	0.310 (7,87)	0.300 (7,62)
C MIN	0.245 (6,22)	0.245 (6,22)	0.220 (5,59)	0.245 (6,22)



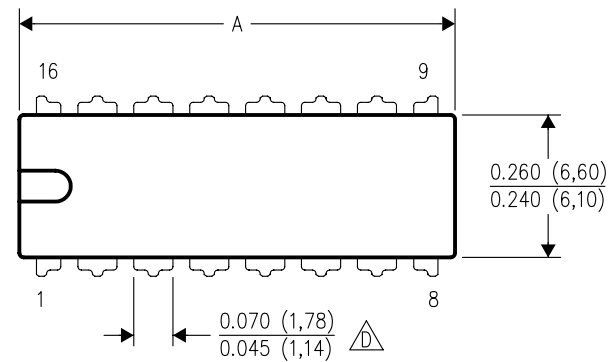
4040083/F 03/03

- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package is hermetically sealed with a ceramic lid using glass frit.
 - D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
 - E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

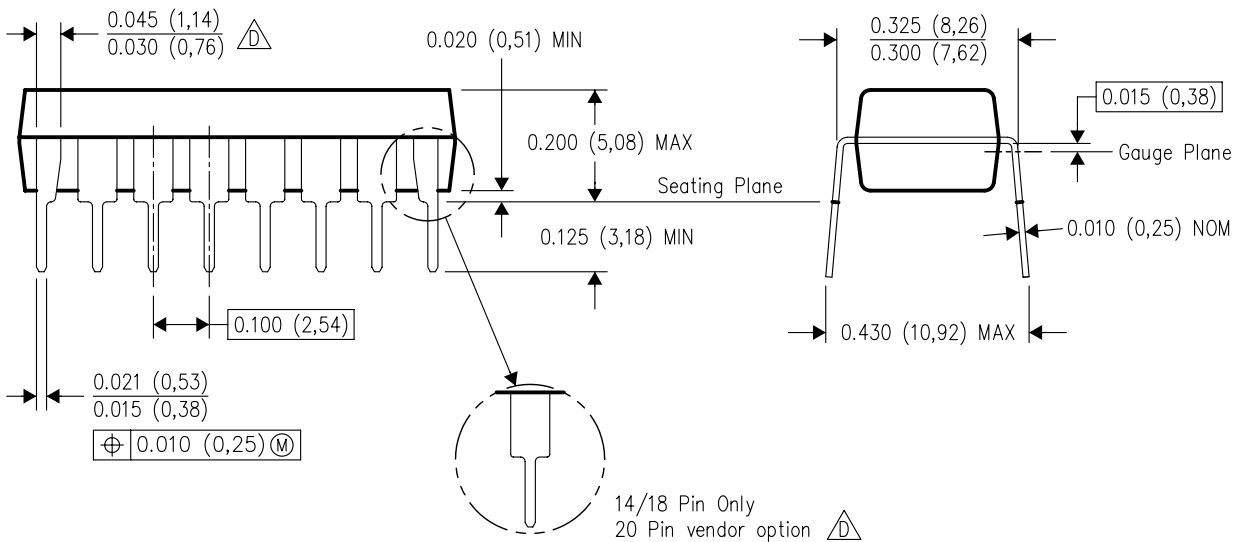
N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



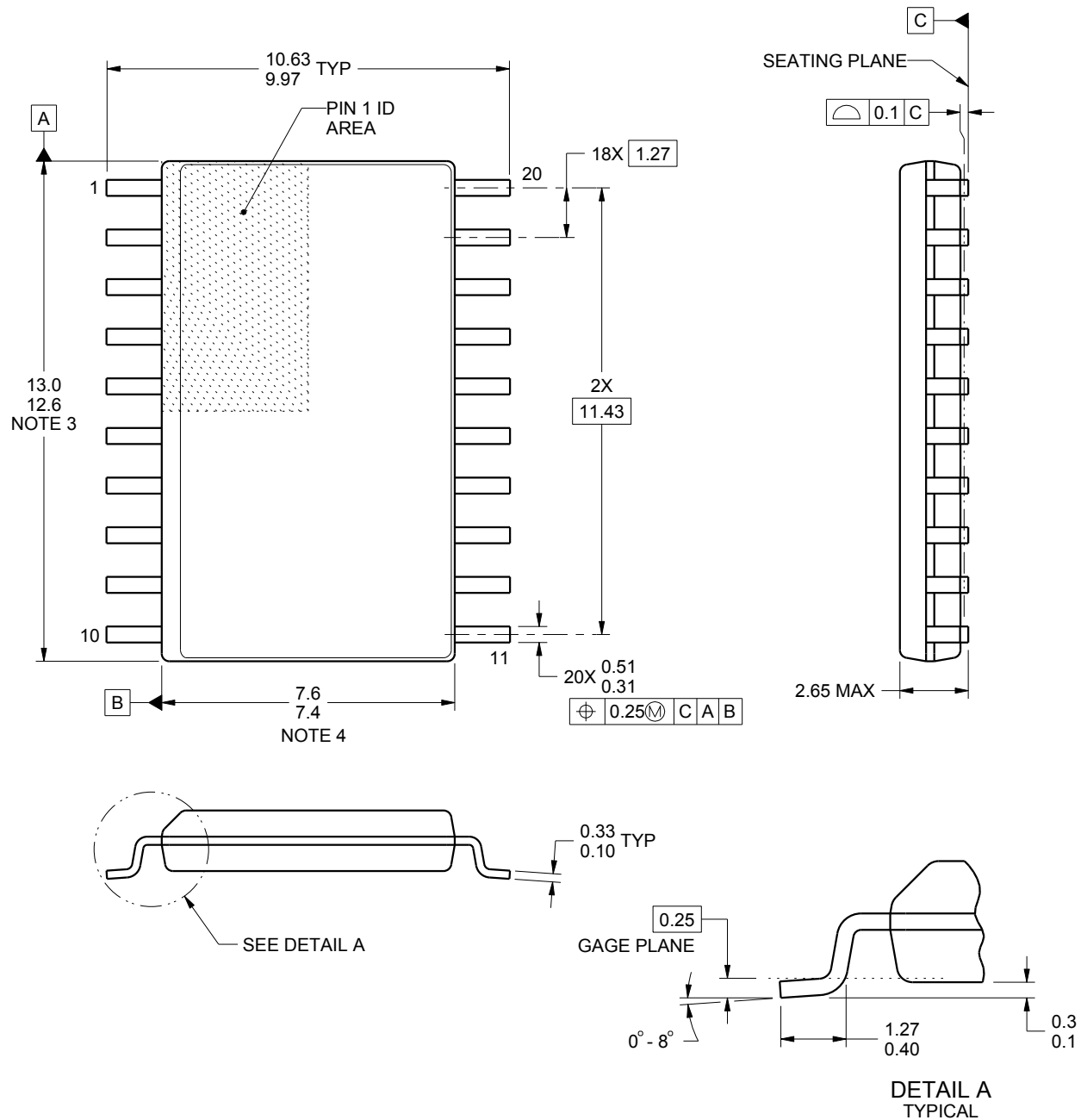
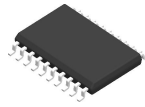
DIM \ PINS **	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS-001 VARIATION	AA	BB	AC	AD



4040049/E 12/2002

NOTES:

- A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
-  Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 The 20 pin end lead shoulder width is a vendor option, either half or full width.



4220724/A 05/2016

NOTES:

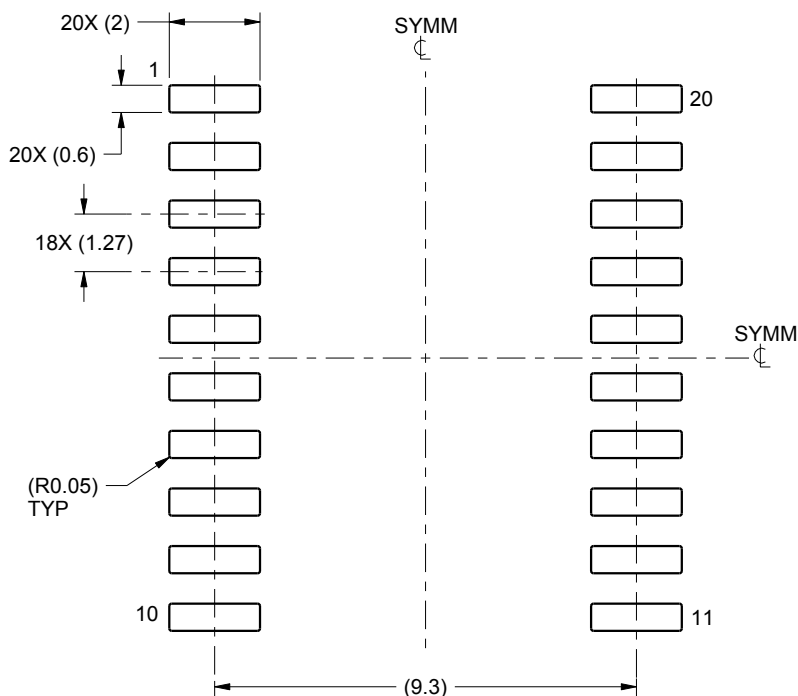
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
5. Reference JEDEC registration MS-013.

EXAMPLE BOARD LAYOUT

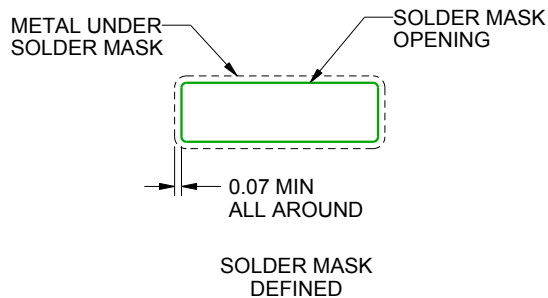
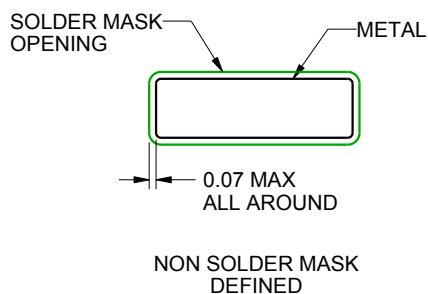
DW0020A

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE
SCALE:6X



SOLDER MASK DETAILS

4220724/A 05/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

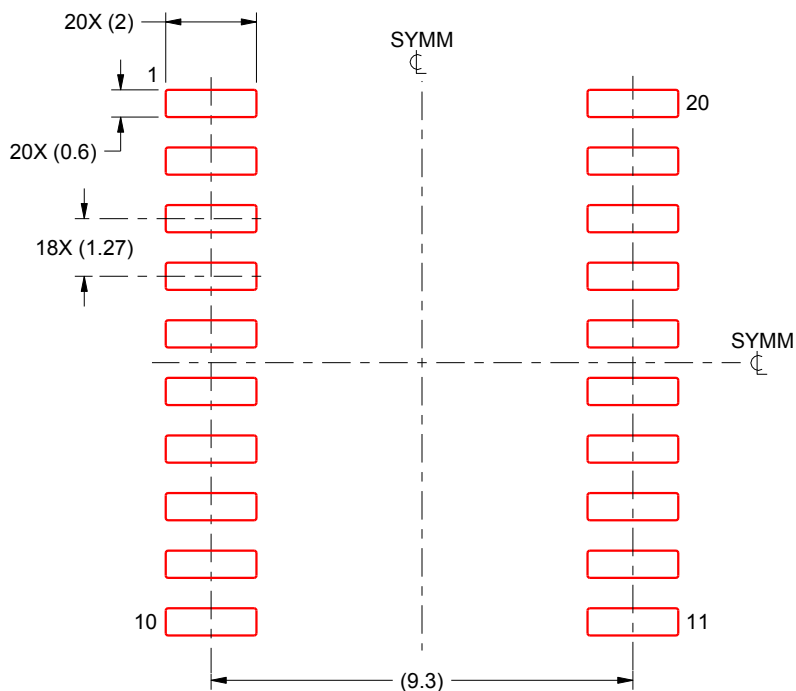
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DW0020A

SOIC - 2.65 mm max height

SOIC



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:6X

4220724/A 05/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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